



3.3V, 2 x 1:5 CMOS Clock Driver

Features

- Low output skew: <200ps →
- Switching frequency up to 166 MHz →
- → Fast output rise/fall time: <1.0ns
- Low propagation delay: <2.5ns →
- Low input capacitance: <6.0pF →
- Balanced CMOS outputs →
- Industrial Temperature: -40°C to +85°C →
- 3.3V ±10% operation, 5V Input Tolerant →
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2) →
- Halogen and Antimony Free. "Green" Device (Note 3) →
- For automotive applications requiring specific change control → (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

- Packaging (Pb-free & Green available): →
 - 20-pin, 150-mil wide QSOP (Q)
 - 20-pin, 209-mil wide SSOP (H)

Block Diagram



Description

Diodes' PI49FCT3805D is composed of non-inverting drivers. The outputs are configured into 2 groups of one-in, five-out with independent output enable. Group B has an extra MON output. Excellent output signals to power and ground ratio minimize power and ground noise and also improves output performance.

Truth	Table ⁽¹⁾
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Inputs		Outputs		
OE X	INX	OAX	MON	
L	L	L	L	
L	Н	Н	Н	
Н	L	Z	L	
Н	Н	Z	Н	

Note:

H = High Voltage Level, L = Low Voltage Level, 1. Z = High Impedance

antimony compounds.

Notes:

^{1.} No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

^{2.} See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm





Pin Configuration

	1 U 20	и и и и и и и и и и и и и и и и и и и
0A0 🗖	2 19	ОВО
OA1 🕻	3 18	ОВ1
0A2 🕻	4 17	ОВ2
GNDA 🕻	5 16	GNDB
OA3 🛙	6 15	р овз
0A4 🗖	7 14	р ов4
GNDQ 🛙	8 13	П мом
OEA 🕻	9 12	D OEB
INA 🗖	10 11	р ілв
		-

Pin Description

Pin Name	Description	
\overline{OE}_X	Hi-Z State Output Enable Inputs (Active Low)	
INX	Clock Inputs	
OA _N , OB _N	Clock Outputs	
MON	Monitor Output	
GND	Ground	
V _{CC}	Power	



Note:



PI49FCT3805D

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature
Ambient Temperature with Power Applied40°C to +85°C
Input Voltage to GND Potential (Inputs & V _{CC} Only) –0.5V to 5.5V
Output Voltage to GND Potential (Outputs & I/O Only)–0.5V to +V _{CC} +0.5V
V _{CC} Input Voltage–0.5V to +4.6V

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Symbol	Parameters	Test Conditions ⁽¹⁾	Min.	Тур.	Max.	Units
V _{OH}	Output High Voltage V_{CC} = Min., V_{IN} = V_{IL} or V_{IH}	$I_{OH} = -0.1mA$ $I_{OH} = -8mA$ $I_{OH} = -12mA$	$\begin{array}{c c} V_{CC}\text{-}0.2 \\ 2.4^{(3)} \\ 2.4^{(3)} \end{array}$	3.0 3.0		
V _{OL}	$\begin{array}{l} \text{Output Low Voltage} \\ \text{V}_{\text{CC}} = \text{Min.,} \\ \text{V}_{\text{IN}} = \text{V}_{\text{IL}} \text{ or } \text{V}_{\text{IH}} \end{array}$	$I_{OH} = 0.1 mA$ $I_{OH} = 8 mA$ $I_{OH} = 12 mA$		0.2 0.3	0.2 0.4 0.4	V
V _{IH}	Input High Voltage	Low Logic	2.0		5.5	
V _{IL}	Input Low Voltage	High Logic	-0.5		0.8	
I _{IH}	Input High Current	V_{CC} = Max., V_{IN} = 5.5V			1	
I _{IL}	Input Low Current	V _{CC} = Max., V _{IN} = GND			-1	μΑ
I _{OZH} I _{OZL}	High Impedance output current				1 -1	, pri
V _{IK}	Clamp Diode Voltage	V_{CC} = Min., I_{IN} = -18mA		-0.7	-1.2	V
I _{ODH}	Output High Current ^(4, 5)	$V_{OUT} = 1.5V$, $V_{IN} = V_{IL}$ or V_{IH} , $V_{CC} = 3.3V$	-40	-74	-100	
I _{ODL}	Output Low Current ^(4, 5)	$V_{OUT} = 1.5V$, $V_{IN} = V_{IL}$ or V_{IH} , $V_{CC} = 3.3V$	50	90	130	mA
I _{OS}	Short Circuit Current ^(4, 5)	V _{CC} = Max., V _{OUT} = GND	-60	-100	-120	

DC Electrical Characteristics ($T_A = -40^{\circ}C$ to $+85^{\circ}C$, $V_{CC} = 3.3V \pm 0.3V$)

Notes:

For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type. 1

Typical values are at $V_{CC} = 3.3V$, $+25^{\circ}C$ ambient and maximum loading. 2.

 $V_{OH} = V_{CC} - 0.6V$ at rated current. 3.

4. This parameter is determined by device characterization but is not production tested.

5. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.

Capacitance ($T_A = 25^{\circ}C$, f = 1 MHz)

Parameters ⁽¹⁾	Description	Test Conditions	Тур	Max.	Units
C _{IN}	Input Capacitance	$V_{IN} = 0V$	3.0	4	чE
C _{OUT}	Output Capacitance	$V_{OUT} = 0V$	—	6	pF

Note:

This parameter is determined by device characterization but is not production tested. 1.





Power Supply Characteristics

Parameters	Description	Test Co	onditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Units
I _{CC}	Quiescent Power Supply Current	V _{CC} = Max.	$V_{IN} = GND \text{ or } V_{DD}$		0.1	30	
I _{DD}	Dynamic Supply Current per Output	$V_{CC} = 3.6V,$ $C_L = 15pF,$ All Outputs Toggling			80	120	μΑ
$V_{CC} = 3.6V,$ $C_{I} = 15pF_{s}$	$V_{CC} = 3.6V,$ $C_{L} = 15pF,$	V _{IN} = V _{CC} or GND		100	135		
Ŧ	Total Power Supply	All Outputs Toggling,	$V_{IN} = V_{CC}$ -0.6V or GND		100	135	mA/
I _C	Current	$V_{CC} = 3.6V,$ $C_{L} = 15pF,$	$V_{IN} = V_{CC}$ or GND		120	160	MHz
	All Outputs Toggling, $f_i = 166 \text{ MHz}$	$V_{IN} = V_{CC}$ -0.6V or GND		120	160		
ΔI_{CC}	Supply Current per inputs @ TTL High	V _{CC} = Max.	$V_{\rm IN} = V_{\rm CC} - 0.6 V^{(3)}$		45	300	μΑ

Notes:

For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device. 1.

Typical values are at $V_{CC} = 3.3V$, $+25^{\circ}C$ ambient. 2.

Per TTL driven input ($V_{IN} = V_{CC} - 0.6V$); all other inputs at V_{CC} or GND. 3.





Switching Characteristics over Operating Range

Demonsterne	Description	Test Conditions ⁽¹⁾	3805D	TT	
Parameters	Description	Test Conditions ^v	Max.	Units	
t _{PLH} t _{PHL}	Propagation Delay IN_N to O_N		3.0	ns	
t _R /t _F	CLKn Rist/Fall Time 0.8V ~ 2.0V		1.5	ns	
$t_{SK(o)}^{(3)}$	Pulse Skew	$C_{L} = 15 pF,$	270		
$t_{SK(p)}^{(3)}$	Output Skew	133 MHz (3805D)	270	ps	
t _{SK(t)} ⁽³⁾	Package Skew		550		
$t_{ZL}, t_{ZH}, t_{LZ}, t_{HZ}$	Enable/Disable Time		5.2	ns	
F _{MAX}	Input Frequency		133	MHz	
Note:		•			

1. These parameters are guaranteed by design

2. Series Resistor loading = 33Ω (See Test Circuit)

Switch Position

Test	Switch
Disable LOW Enable LOW	6V
Disable HIGH Enable HIGH	GND
All Other Inputs	Open

Definitions:

 C_L = Load capacitance: includes jig and probe capacitance. 1.

2. R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

Tests Circuit



Enable/Disable Time Test Set-Up







Switching Waveforms



Enable and Disable Times



Package Skew – tsk(t)





tSK(o) = | tPLHy Đ tPLHx | or | tPHLy Đ tPHLx |

Pulse Skew – tsk(p)







Part Marking

H Package



YY: Year WW: Workweek 1st X: Assembly Code 2nd X: Fab Code

Q Package



YY: Year WW: Workweek 1st X: Assembly Code 2nd X: Fab Code





Packaging Mechanical: 20-SSOP (H)



13-0214





Packaging Mechanical: 20-QSOP (Q)



For latest package info.

 $please \ check: \ http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/pericom-packaging/packaging-pericom-packaging-packaging-pericom-packaging-packaging-packaging-packaging-packaging-packaging-packaging-packaging-packaging-packaging-packaging$

Ordering Information

Ordering Code	Package Code	Package Description
PI49FCT3805DHEX	Н	20-pin, 209-mil Wide (SSOP)
PI49FCT3805DQEX	Q	20-pin, 150-mil Wide (QSOP)

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. E = Pb-free and Green

5. X suffix = Tape/Reel





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